MSKSEMI















ESD

TVS

TSS

MOV

GDT

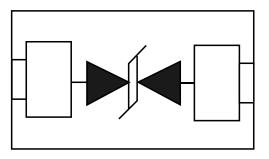
PLED

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Features

- Small Body Outline Dimensions: 0.039" x 0.024" (1.0 mm x 0.60 mm)
- Protects one I/O or power line
- Low Clamping Voltage
- Ultra Low Capacitance: 0.9pF
- Working Voltage: 5 V
- Low Leakage Current
- Response Time is Typically < 1 ns



SOD-882

IEC COMPATIBILITY (EN61000-4)

- IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)

Mechanical Characteristics

- **DFN1006**
- Molding compound flammability rating: UL 94V-0
- Marking: Marking Code
- Packaging: Tape and Reel per EIA 481
- **RoHS/WEEE Compliant**

Applications

- **Laptop Computers**
- Cellular Phones
- **Digital Cameras**
- Personal Digital Assistants (PDAs)

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

P/N	V _{RWM} (V)	I _R (μΑ) @ V _{RWM}	V _{BR} (V) @ I _T (Note 2)	Ι _Τ	C (pF)	V _C (V) @ I _{PP} = 1 A (Note 3)	Vc
	Max	Max	Min	mA	Max	Max	Per IEC61000-4-2 (Note 4)
ESD9L5.0ST5G-MS	5.0	1.0	5.4	1.0	0.9	12.9	Figures 1 and 2 See Below

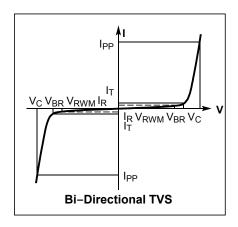
- 2. V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C.
- 3. Surge current waveform per Figure 4.
- 4. For test procedure see Figures 3.



ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Parameter		
I _{PP}	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
V _{RWM}	Working Peak Reverse Voltage		
I _R	Maximum Reverse Leakage Current @ V _{RWM}		
V_{BR}	Breakdown Voltage @ I _T		
lτ	Test Current		
lF	Forward Current		
V _F	Forward Voltage @ I _F		
P _{pk}	Peak Power Dissipation		
С	Capacitance @ V _R = 0 and f = 1.0 MHz		



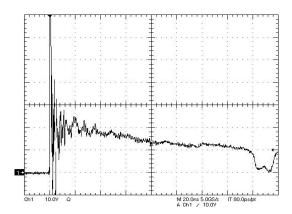


Figure 1. ESD Clamping Voltage Screenshot Positive 8 kV Contact per IEC61000-4-2

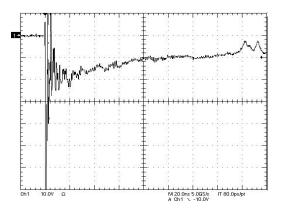
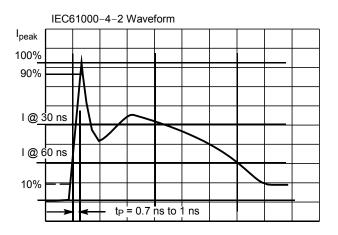


Figure 2. ESD Clamping Voltage Screenshot Negative 8 kV Contact per IEC61000-4-2



IEC 61000-4-2 Spec.

Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8



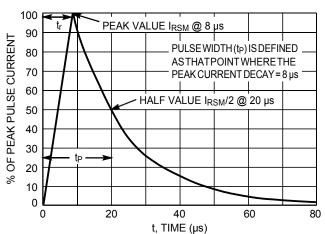
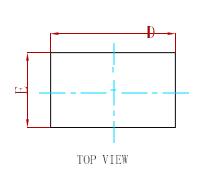
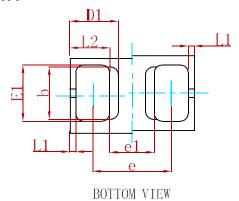


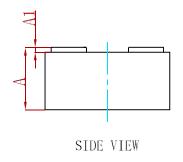
Figure 4. 8 X 20 µs Pulse Waveform



PACKAGE MECHANICAL DATA







6 1 1	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
A	0.450	0.550	0.018	0.022
A1	0.010	0.090	0.000	0.004
D	0.950	1.050	0.037	0.041
Е	0.550	0.650	0.022	0.026
D1	0.390REF.		0.015REF.	
E1	0.400	0.500	0.016	0.020
b	0.420REF.		0.017REF.	
e	0.580	0.680	0.023	0.027
e1	0.360REF.		0.014REF.	
L1	0.050REF.		0.002REF.	
L2	0.270	0.370	0.011	0.015

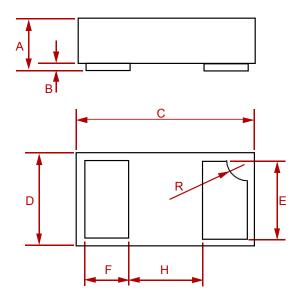
REEL SPECIFICATION

P/N	PKG	QTY
ESD9L5.0ST5G-MS	SOD-882	10000



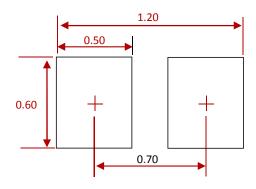


PACKAGE MECHANICAL DATA



Dim	Inc	hes	Millimeters		
Dim	MIN	MAX	MIN	MAX	
Α	0.0125	0.02	0.32	0.52	
В	0.000	0.002	0.00	0.05	
С	0.037	0.043	0.95	1.080	
D	0.022	0.027	0.55	0.680	
E	0.016	0.024	0.40	0.60	
F	0.008	0.012	0.20	0.30	
Н	0.015Typ.		0.40Тур.		
R	0.001	0.005	0.05	0.15	

Suggested Pad Layout



NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

REEL SPECIFICATION

P/N	PKG	QTY
ESD9L5.0ST5G-MS	SOD-882	10000



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